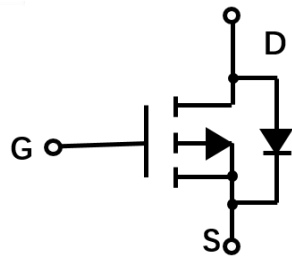
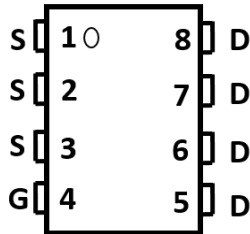


SOP-8



Product Summary

- V_{DS} -30V
- I_D -10A
- $R_{DS(ON)}$ (at $V_{GS}=-10V$) <23 mohm
- $R_{DS(ON)}$ (at $V_{GS}=-4.5V$) <34 mohm

General Description

- Trench Power LV MOSFET technology
- High density cell design for Low $R_{DS(ON)}$
- High Speed switching

Applications

- Battery protection
- Load switch
- Power management

■ Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Maximum | Unit |
|--|-----------------|---------------------------------|--------------|
| Drain-source Voltage | V_{DS} | -30 | V |
| Gate-source Voltage | V_{GS} | ± 20 | V |
| Drain Current | I_D | $T_A=25^\circ C$ @ Steady State | -10 |
| | | $T_A=70^\circ C$ @ Steady State | -8 |
| Pulsed Drain Current ^A | I_{DM} | -50 | A |
| Total Power Dissipation @ $T_A=25^\circ C$ | P_D | 3.0 | W |
| Thermal Resistance Junction-to-Ambient @ Steady State ^B | $R_{\theta JA}$ | 42 | $^\circ C/W$ |
| Junction and Storage Temperature Range | T_J, T_{STG} | -55~+150 | $^\circ C$ |

■ Ordering Information (Example)

| PREFERRED P/N | PACKING CODE | Marking | MINIMUM PACKAGE(pcs) | INNER BOX QUANTITY(pcs) | OUTER CARTON QUANTITY(pcs) | DELIVERY MODE |
|---------------|--------------|---------|----------------------|-------------------------|----------------------------|---------------|
| LMS4435A | F2 | Q4435A | 4000 | 8000 | 64000 | 13" reel |

■ Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Conditions | Min | Typ | Max | Units |
|---------------------------------------|--------------|--|------|------|-----------|------------|
| Static Parameter | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS}=0V, I_D=-250\mu A$ | -30 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=-30V, V_{GS}=0V, T_C=25^\circ\text{C}$ | | | -1 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | | | ± 100 | nA |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$ | -1.0 | -1.5 | -2.5 | V |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS}=-10V, I_D=-10A$ | | 16 | 23 | m Ω |
| | | $V_{GS}=-4.5V, I_D=-5.0A$ | | 21.5 | 34 | |
| Diode Forward Voltage | V_{SD} | $I_S=-10A, V_{GS}=0V$ | | -0.8 | -1.2 | V |
| Maximum Body-Diode Continuous Current | I_S | | | | -10 | A |
| Dynamic Parameters | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=-15V, V_{GS}=0V, f=1\text{MHz}$ | | 1500 | | pF |
| Output Capacitance | C_{oss} | | | 327 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 276 | | |
| Switching Parameters | | | | | | |
| Total Gate Charge | Q_g | $V_{GS}=-10V, V_{DS}=-15V, I_D=-9.1A$ | | 30 | | nC |
| Gate Source Charge | Q_{gs} | | | 5.3 | | |
| Gate Drain Charge | Q_{gd} | | | 7.6 | | |
| Turn-on Delay Time | $t_{D(on)}$ | $V_{GS}=-10V, V_{DS}=-15V, I_D=-6A, R_{GEN}=2.5\Omega$ | | 14 | | ns |
| Turn-on Rise Time | t_r | | | 20 | | |
| Turn-off Delay Time | $t_{D(off)}$ | | | 95 | | |
| Turn-off Fall Time | t_f | | | 65 | | |

- A. Repetitive Rating: Pulse width limited by maximum junction temperature.
 B. Surface Mounted on FR4 Board, $t \leq 10$ sec.

■ Typical Performance Characteristics

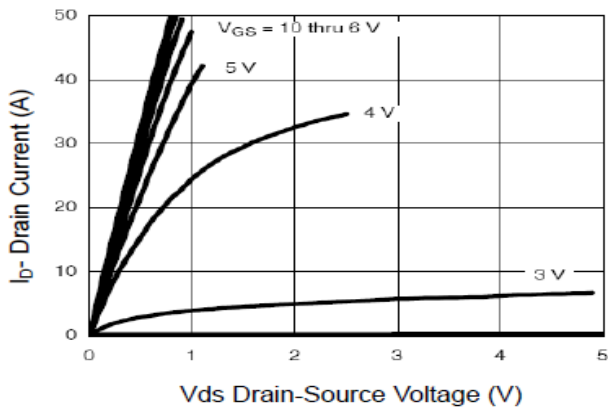


Figure1. Output Characteristics

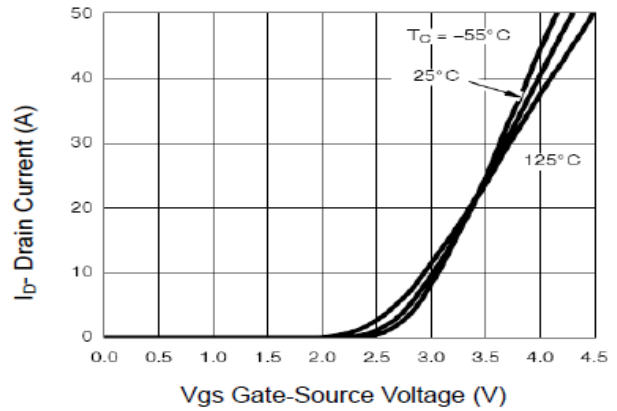


Figure2. Transfer Characteristics

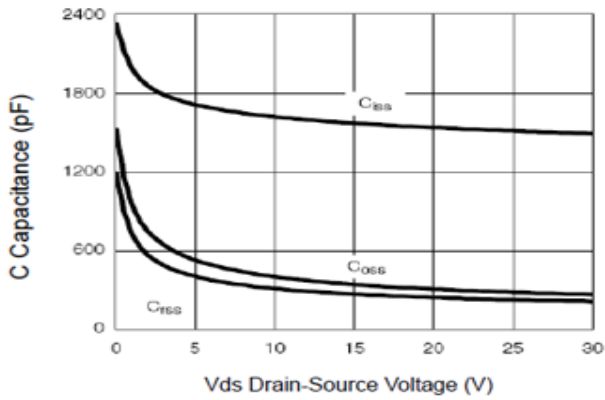


Figure3. Capacitance Characteristics

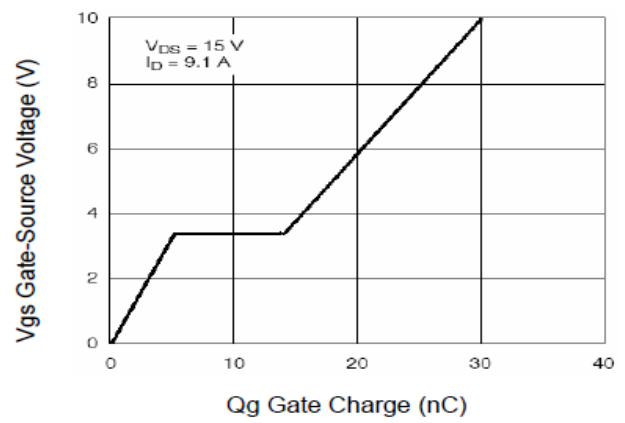


Figure4. Gate Charge

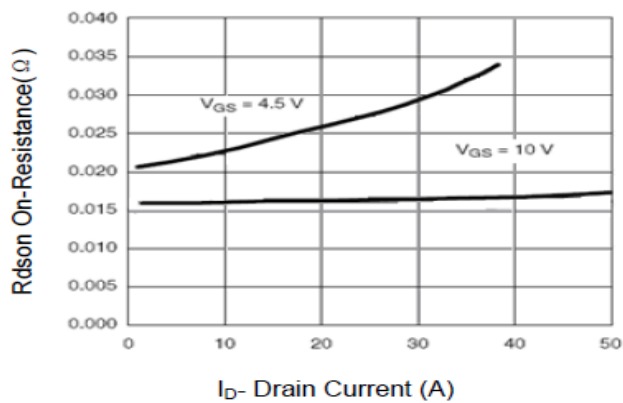


Figure5. Drain-Source on Resistance

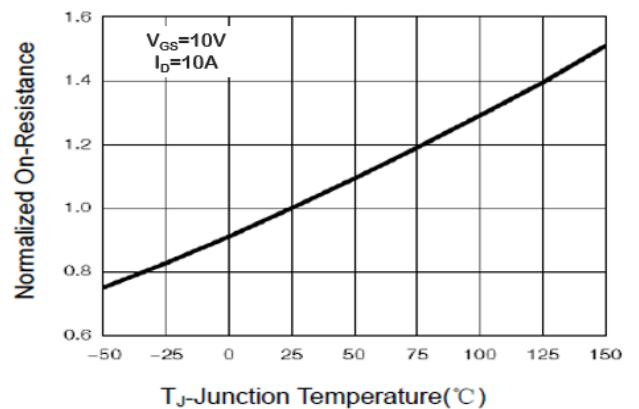


Figure6. Drain-Source on Resistance

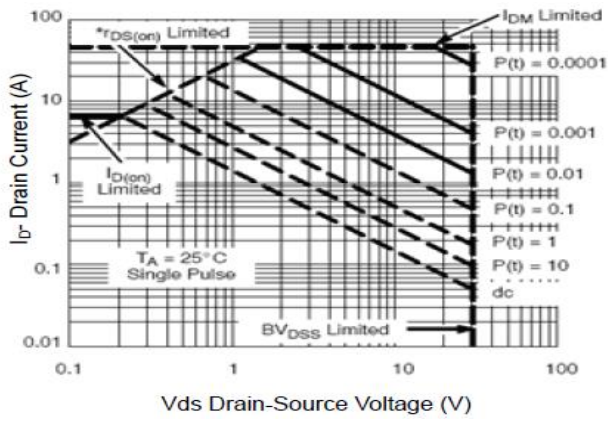


Figure7. Safe Operation Area

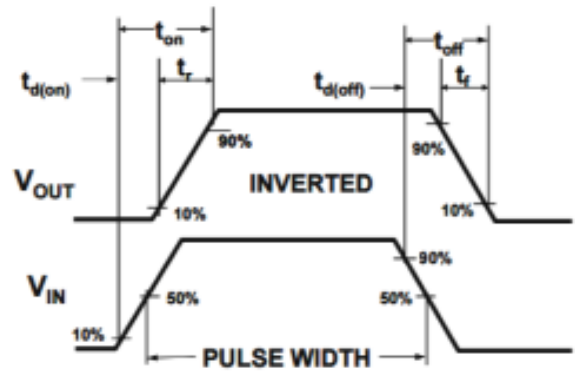
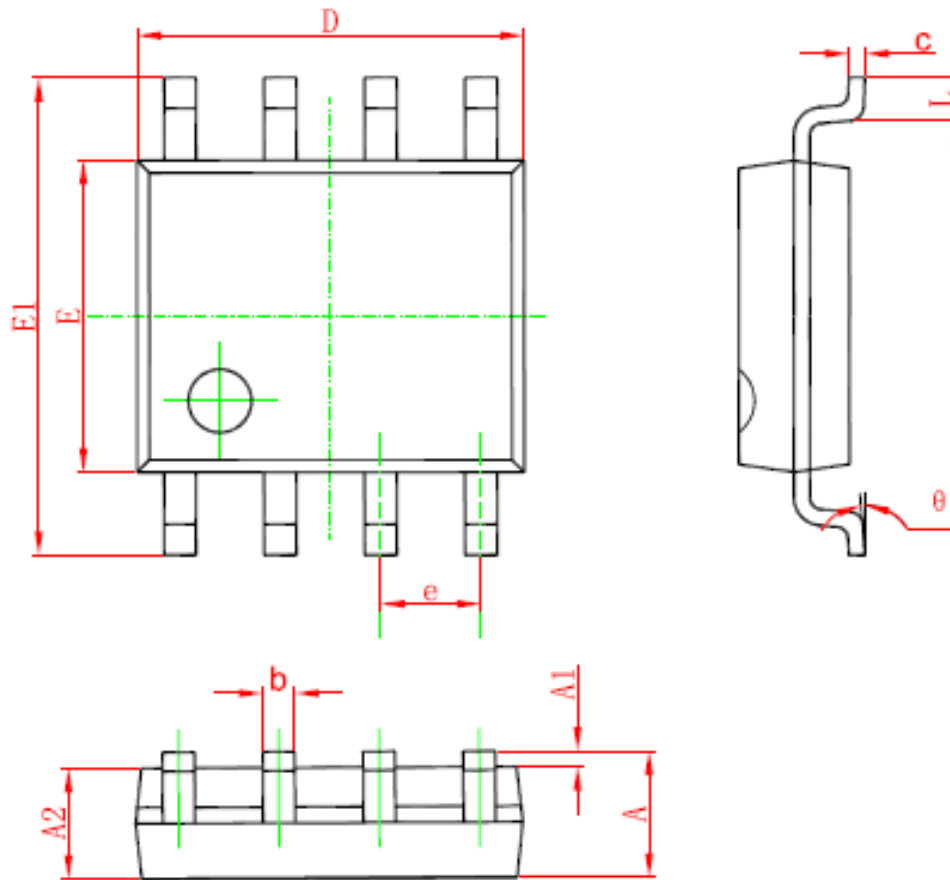


Figure8. Switching wave

■ SOP-8 Package information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|-------|----------------------|-------|
| | Min | Max | Min | Max |
| A | 1.350 | 1.750 | 0.053 | 0.069 |
| A1 | 0.100 | 0.250 | 0.004 | 0.010 |
| A2 | 1.350 | 1.550 | 0.053 | 0.061 |
| b | 0.330 | 0.510 | 0.013 | 0.020 |
| c | 0.170 | 0.250 | 0.006 | 0.010 |
| D | 4.700 | 5.100 | 0.185 | 0.200 |
| E | 3.800 | 4.000 | 0.150 | 0.157 |
| E1 | 5.800 | 6.200 | 0.228 | 0.244 |
| e | 1.270 (BSC) | | 0.050 (BSC) | |
| L | 0.400 | 1.270 | 0.016 | 0.050 |
| theta | 0° | 8° | 0° | 8° |

Shanghai Leiditech Electronic Co.,Ltd
 Email: sale1@leiditech.com
 Tel : +86- 021 50828806
 Fax : +86- 021 50477059